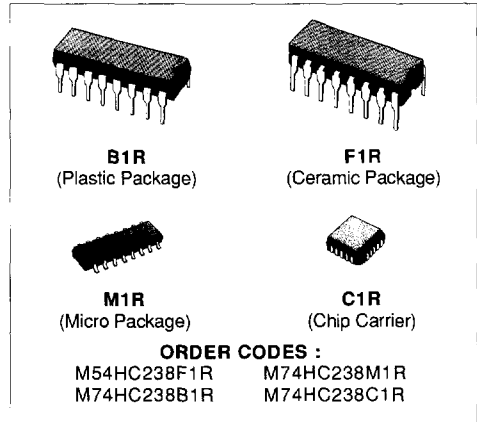


3 TO 8 LINE DECODER

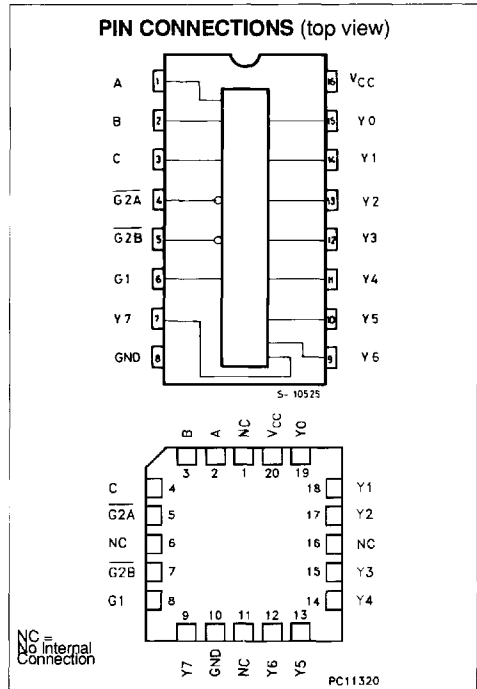
- HIGH SPEED
 $t_{PD} = 14 \text{ ns (TYP.) AT } V_{CC} = 5 \text{ V}$
- LOW POWER DISSIPATION
 $I_{CC} = 4 \mu\text{A (MAX.) AT } T_A = 25 \text{ }^\circ\text{C}$
- HIGH NOISE IMMUNITY
 $V_{NIH} = V_{NIL} = 28 \% V_{CC} \text{ (MIN.)}$
- OUTPUT DRIVE CAPABILITY
 10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
 $|I_{OH}| = I_{OL} = 4 \text{ mA (MIN.)}$
- BALANCED PROPAGATION DELAYS
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
 $V_{CC} \text{ (OPR.)} = 2 \text{ V TO } 6 \text{ V}$
- PIN AND FUNCTION COMPATIBLE
 WITH 54/74LS238



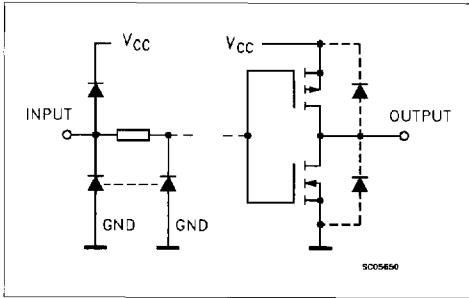
DESCRIPTION

The M54/74HC238 is a high speed CMOS 3 to 8 line decoder fabricated in silicon gate C^2 MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption. If the device is enabled, 3 binary select inputs (A, B and C) determine which one of outputs will go high. Enable input G1 is held "Low" or either G2A or G2B is held "High" decoding function is inhibited and all the 8 outputs go low. Three enable inputs are provided to ease cascade connection and application of this address decoder in memory systems.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.



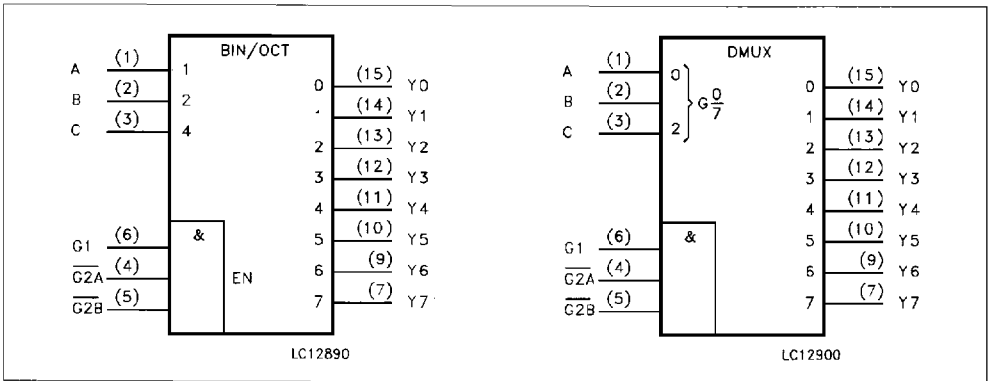
INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 2, 3	A, B, C	Data Inputs
4, 5	G2A G2B	Enable Input (Active LOW)
6	G1	Data Enable Input (Active HIGH)
15, 14, 13, 12, 11, 10, 9, 7	Y0 to Y7	Outputs
8	GND	Ground (0V)
16	V _{CC}	Positive Supply Voltage

IEC LOGIC SYMBOLS

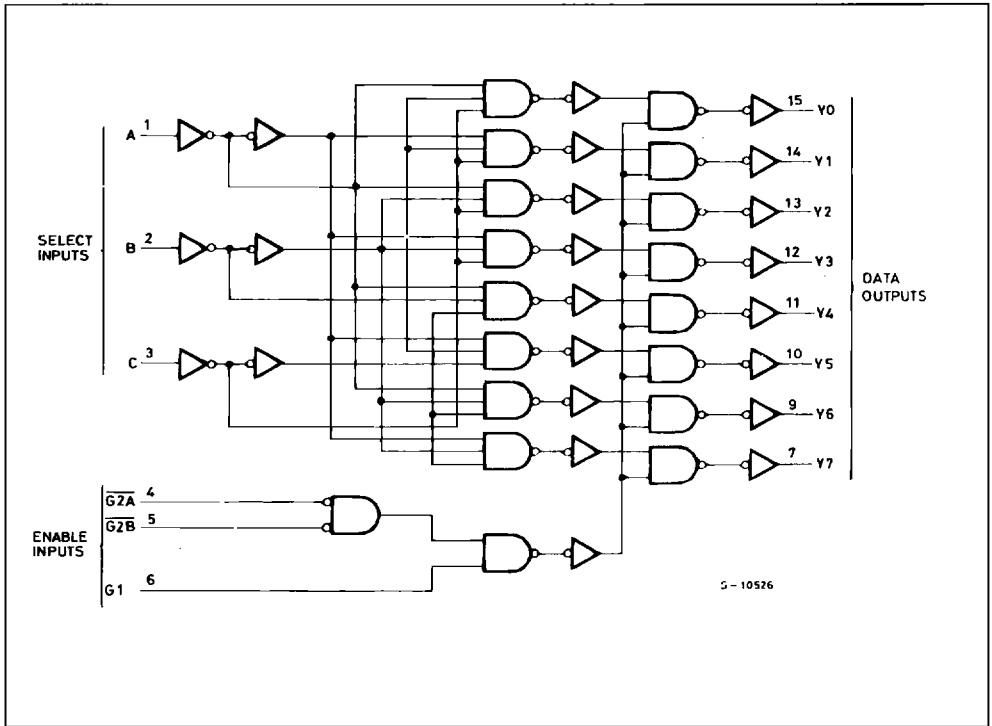


TRUTH TABLE

INPUTS						OUTPUTS								SELECTED OUTPUT
ENABLE			SELECT											
G2B	G2A	G1	C	B	A	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7	
X	X	L	X	X	X	L	L	L	L	L	L	L	L	NONE
X	H	X	X	X	X	L	L	L	L	L	L	L	L	NONE
H	X	X	X	X	X	L	L	L	L	L	L	L	L	NONE
L	L	H	L	L	L	H	L	L	L	L	L	L	L	Y0
L	L	H	L	L	H	L	H	L	L	L	L	L	L	Y1
L	L	H	L	H	L	L	L	H	L	L	L	L	L	Y2
L	L	H	L	H	H	L	L	L	H	L	L	L	L	Y3
L	L	H	H	L	L	L	L	L	L	H	L	L	L	Y4
L	L	H	H	L	H	L	L	L	L	L	H	L	L	Y5
L	L	H	H	H	L	L	L	L	L	L	L	H	L	Y6
L	L	H	H	H	H	L	L	L	L	L	L	L	H	Y7

X: Don't Care

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to +150	$^{\circ}C$
T_L	Lead Temperature (10 sec)	300	$^{\circ}C$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: $\approx 65^{\circ}C$ derate to 300 mW by 10mW/ $^{\circ}C$: 65 $^{\circ}C$ to 85 $^{\circ}C$

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	2 to 6	V
V_I	Input Voltage	0 to V_{CC}	V
V_O	Output Voltage	0 to V_{CC}	V
T_{op}	Operating Temperature: M54HC Series M74HC Series	-55 to +125 -40 to +85	°C °C
t_r, t_f	Input Rise and Fall Time	$V_{CC} = 2\text{ V}$	0 to 1000
		$V_{CC} = 4.5\text{ V}$	0 to 500
		$V_{CC} = 6\text{ V}$	0 to 400

DC SPECIFICATIONS

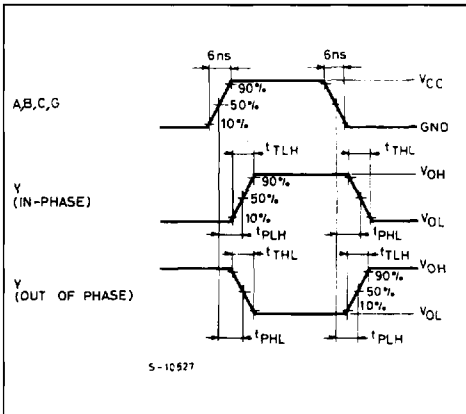
Symbol	Parameter	Test Conditions		Value						Unit	
				$T_A = 25\text{ °C}$ 54HC and 74HC			$-40\text{ to }85\text{ °C}$ 74HC		$-55\text{ to }125\text{ °C}$ 54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V_{IH}	High Level Input Voltage	V_{CC} (V)		1.5			1.5		1.5	V	
				3.15			3.15		3.15		
				4.2			4.2		4.2		
V_{IL}	Low Level Input Voltage	V_{CC} (V)				0.5		0.5	0.5	V	
						1.35		1.35	1.35		
						1.8		1.8	1.8		
V_{OH}	High Level Output Voltage	V_{CC} (V)	$V_I = V_{IH}$ or V_{IL}	$I_O = -20\text{ }\mu\text{A}$	1.9	2.0		1.9		1.9	V
					4.4	4.5		4.4		4.4	
			$V_I = V_{IH}$ or V_{IL}	$I_O = -4.0\text{ mA}$	5.9	6.0		5.9		5.9	
					4.18	4.31		4.13		4.10	
V_{OL}	Low Level Output Voltage	V_{CC} (V)	$V_I = V_{IH}$ or V_{IL}	$I_O = 20\text{ }\mu\text{A}$		0.0	0.1		0.1	0.1	V
							0.0	0.1		0.1	
			$V_I = V_{IH}$ or V_{IL}	$I_O = 4.0\text{ mA}$		0.17	0.26		0.33	0.40	
						0.18	0.26		0.33	0.40	
I_i	Input Leakage Current	$V_I = V_{CC}$ or GND			± 0.1		± 1		± 1	μA	
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND			4		40		80	μA	

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

Symbol	Parameter	Test Conditions		Value						Unit	
		V_{CC} (V)		$T_A = 25^\circ\text{C}$			$-40 \text{ to } 85^\circ\text{C}$		$-55 \text{ to } 125^\circ\text{C}$		
				54HC and 74HC			74HC		54HC		
Min.	Typ.	Max.	Min.	Max.	Min.	Max.					
t_{TLH} t_{THL}	Output Transition Time	2.0 4.5 6.0		30 8 7	75 15 13		95 19 16		110 22 19	ns	
t_{PLH} t_{PHL}	Propagation Delay Time (A, B, C - Y)	2.0 4.5 6.0		50 17 15	150 30 26		190 38 32		225 45 38	ns	
t_{PLH} t_{PHL}	Propagation Delay Time (G1 - Y)	2.0 4.5 6.0		50 17 15	150 30 26		190 38 32		225 45 38	ns	
t_{PLH} t_{PHL}	Propagation Delay Time (G2 - Y)	2.0 4.5 6.0		50 17 15	150 30 26		190 38 32		225 45 38	ns	
C_{IN}	Input Capacitance			5	10		10		10	pF	
$C_{PD} (*)$	Power Dissipation Capacitance			53						pF	

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST WAVEFORM

TEST CIRCUIT I_{CC} (Opr.)